45 V, 0.5 A, General Purpose NPN Transistor

ON Semiconductor's BC817–40W is a General Purpose NPN Transistor that is housed in the SC–70/SOT–323 package.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- This Device is Pb–Free, Halogen Free/BFR Free and is RoHS Compliant

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	45	V
Collector – Base Voltage	V _{CBO}	50	V
Emitter – Base Voltage	V _{EBO}	5.0	V
Collector Current – Continuous	Ι _C	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation (Note 1)	PD	460	mW
Thermal Resistance, Junction-to-Ambient (Note 1)	R_{\thetaJA}	272	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C

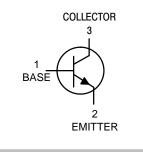
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 Board, 1 oz. Cu, 100 mm²



ON Semiconductor®

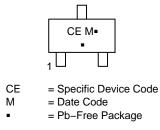
www.onsemi.com





CASE 419 STYLE 3

MARKING DIAGRAM



(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION[†]

Device	Package	Shipping
BC817-40WT1G	SC–70 (Pb–Free)	3000 / Tape & Reel
NSVBC817-40WT1G	SC–70 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

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BC817-40W

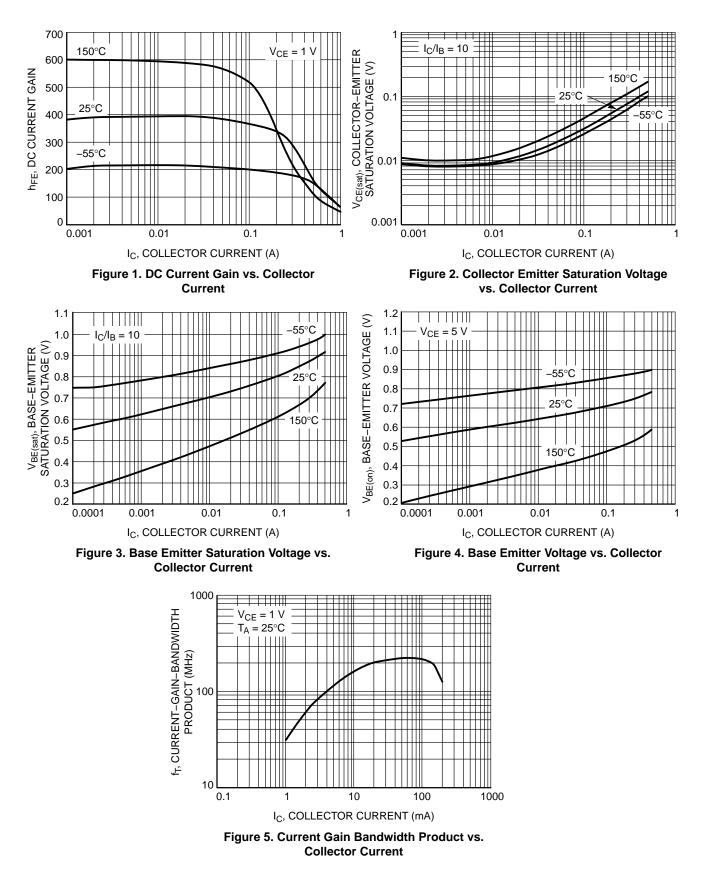
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mA})$	V _{(VR)CEO}	45	-	-	V
Collector – Emitter Breakdown Voltage $(V_{EB} = 0 \text{ V}, I_C = 10 \mu \text{A})$	V _{(VR)CES}	50	-	-	V
Emitter – Base Breakdown Voltage ($I_E = 1.0 \ \mu A$)	V _{(VR)EBO}	5.0	-	-	V
Collector Cutoff Current $(V_{CB} = 20 V)$ $(V_{CB} = 20 V, T_A = 150^{\circ}C)$	Ісво			100 5.0	nA μA
ON CHARACTERISTICS					
DC Current Gain (Note 2) (I _C = 100 mA, V _{CE} = 1.0 V) (I _C = 500 mA, V _{CE} = 1.0 V)	h _{FE}	250 40		600 -	-
Collector – Emitter Saturation Voltage (Note 2) ($I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$)	V _{CE(sat)}	-	-	0.7	V
Base – Emitter On Voltage (Note 2) ($I_C = 500$ mA, $V_{CE} = 1.0$ V)	V _{BE(on)}	-	-	1.2	V
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 100 \text{ MHz}$)	f _T	100	-	-	MHz
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	C _{obo}	_	10	-	pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Condition: Pulse Width = $300 \ \mu$ sec, Duty Cycle $\leq 2\%$

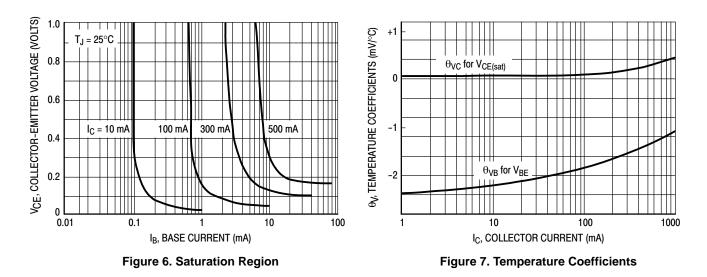
BC817-40W

TYPICAL CHARACTERISTICS



BC817-40W

TYPICAL CHARACTERISTICS



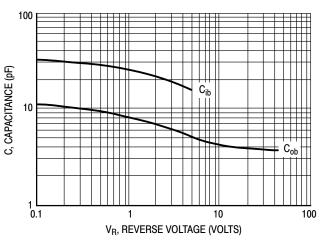


Figure 8. Capacitances

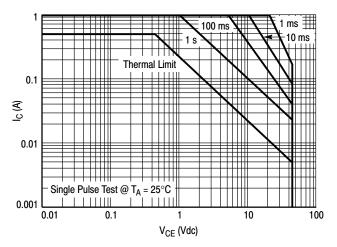
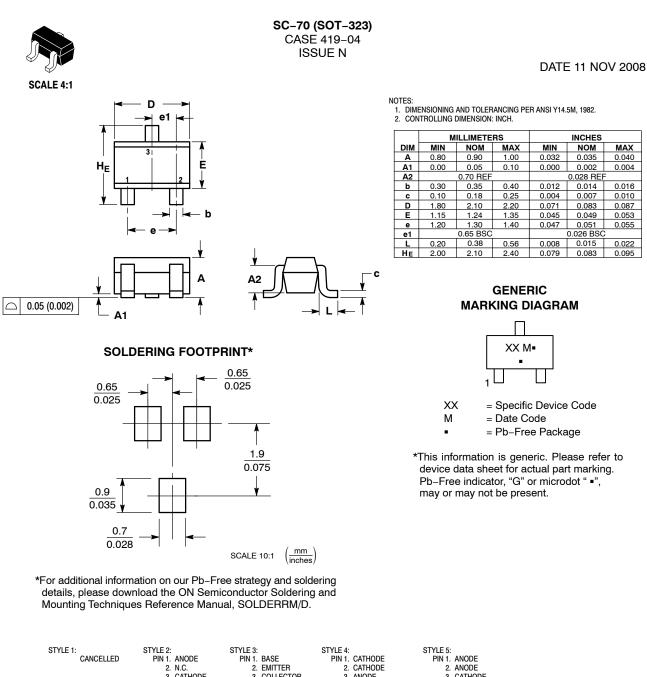


Figure 9. Safe Operating Area





		3. CATHODE	3. COLLECTOR	3. ANODE	3. CATHODE	
3. COLLECTOR 3. COLLECTOR 3. DRAIN 3. CATHODE-ANODE 3. ANODE-CATHODE 3. CATHOD	PIN 1. EMITTER 2. BASE	PIN 1. BASE 2. EMITTER	PIN 1. GATE 2. SOURCE	PIN 1. ANODE 2. CATHODE	PIN 1. CATHODE 2. ANODE	Style 11: Pin 1. Cathode 2. Cathode 3. Cathode

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DESCRIPTION:	SC-70 (SOT-323)		PAGE 1 OF 1	

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